

2N3439

Product Preview Low Power Transistor

NPN Silicon

Features

- MIL-PRF-19500/368 Qualified
- Available as JAN, JANTX, and JANTXV
- Hermetically Sealed Commercial Product with Option for Military Temperature Range Screening

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Value	Unit
Collector - Emitter Voltage	V_{CEO}	350	Vdc
Collector - Base Voltage	V_{CBO}	450	Vdc
Emitter - Base Voltage	V_{EBO}	7.0	Vdc
Collector Current - Continuous	I_C	1.0	Adc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$	P_T	800	mW
Total Device Dissipation @ $T_C = 25^\circ\text{C}$	P_T	5.0	W
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

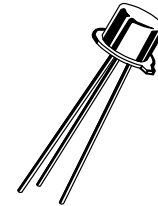
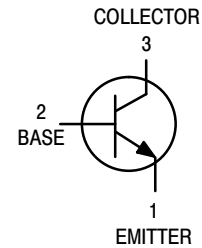
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	175	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	30	$^\circ\text{C}/\text{W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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TO-39
CASE 205AB
STYLE 1

ORDERING INFORMATION

Device	Package	Shipping
2N3439	TO-39	Bulk

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
Emitter-Base Cutoff Current ($V_{EB} = 7.0\text{ Vdc}$)	I_{EBO}	-	10	μAdc
Collector-Emitter Cutoff Current ($V_{CE} = 300\text{ Vdc}$)	I_{CEO}	-	2.0	μAdc
Collector-Emitter Cutoff Current ($V_{CE} = 450\text{ Vdc}$, $V_{BE} = -1.5\text{ Vdc}$)	I_{CEX}	-	5.0	μAdc
Collector-Base Cutoff Current ($V_{CE} = 360\text{ Vdc}$) ($V_{CE} = 450\text{ Vdc}$) ($V_{CE} = 360\text{ Vdc}$, $T_A = 150^\circ\text{C}$)	I_{CBO}	- - -	2.0 5.0 6.0	μAdc
DC Current Gain (Note 1) ($I_C = 0.2\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$) ($I_C = 2.0\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$) ($I_C = 20\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$) ($I_C = 20\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$, $T_A = -55^\circ\text{C}$)	h_{FE}	10 30 40 15	- - 160 -	-
Collector-Emitter Saturation Voltage (Note 1) ($I_C = 50\text{ mAdc}$, $I_B = 4.0\text{ mAdc}$)	$V_{CE(sat)}$	-	0.5	Vdc
Base-Emitter Saturation Voltage (Note 1) ($I_C = 50\text{ mAdc}$, $I_B = 4.0\text{ mAdc}$)	$V_{BE(sat)}$	-	1.3	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $100\text{ kHz} \leq f \leq 1.0\text{ MHz}$)	C_{obo}	-	10	pF
Input Capacitance ($V_{CB} = 5.0\text{ Vdc}$, $I_E = 0$, $100\text{ kHz} \leq f \leq 1.0\text{ MHz}$)	C_{ibo}	-	75	pF
Small-Signal Short-Circuit Forward Current Transfer Ratio ($I_C = 5.0\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$, $f = 1.0\text{ kHz}$)	h_{fe}	25	-	-
Small-Signal Current Gain ($I_C = 10\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$, $f = 5.0\text{ MHz}$)	$ h_{fe} $	3.0	15	-
SWITCHING CHARACTERISTICS				
Turn-on Time (Note 2) ($V_{CC} = 200\text{ Vdc}$, $I_C = 20\text{ mAdc}$, $I_{B1} = 2.0\text{ mAdc}$)	t_{on}	-	1.0	μs
Turn-off Time (Note 2) ($V_{CC} = 200\text{ Vdc}$, $I_C = 20\text{ mAdc}$, $I_{B1} = -I_{B2} = 2.0\text{ mAdc}$)	t_{off}	-	10	μs

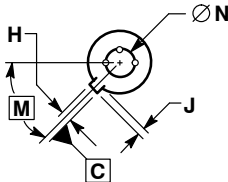
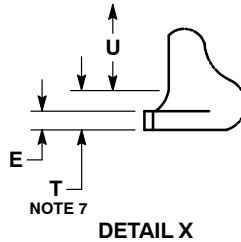
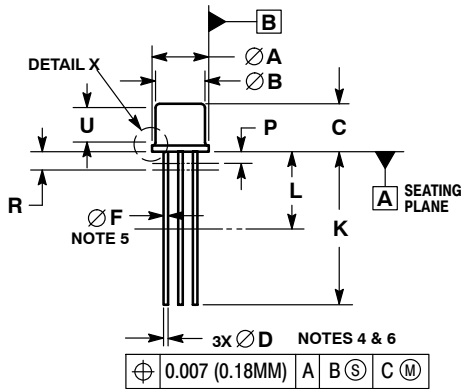
1. Pulse Test: See section 4 of MIL-STD-750.

2. See Figure 14 in MIL-PRF-19500/368.

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PACKAGE DIMENSIONS

TO-39 3-Lead CASE 205AB-01 ISSUE O



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSION J MEASURED FROM DIAMETER A TO EDGE.
4. LEAD TRUE POSITION TO BE DETERMINED AT THE GAUGE PLANE DEFINED BY DIMENSION R.
5. DIMENSION F APPLIES BETWEEN DIMENSION P AND L.
6. DIMENSION D APPLIES BETWEEN DIMENSION L AND K.
7. BODY CONTOUR OPTIONAL WITHIN ZONE DEFINED BY DIMENSIONS A, B, AND T.
8. DIMENSION B SHALL NOT VARY MORE THAN 0.010 IN ZONE P.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.89	9.40	0.350	0.370
B	8.00	8.51	0.315	0.335
C	6.10	6.60	0.240	0.260
D	0.41	0.48	0.016	0.019
E	0.23	3.18	0.009	0.125
F	0.41	0.48	0.016	0.019
H	0.71	0.86	0.028	0.034
J	0.73	1.02	0.029	0.040
K	12.70	14.73	0.500	0.580
L	6.35	---	0.250	---
M	---	---	45° BSC	45° BSC
N	---	---	5.08 BSC	0.200 BSC
P	---	1.27	---	0.050
R	---	1.37 BSC	---	0.054 BSC
T	---	0.76	---	0.030
U	2.54	---	0.100	---

STYLE 1:

1. PIN 1. EMITTER
2. BASE
3. COLLECTOR

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